Quad Operational Amplifier, High Speed with Enables

RHD5902

Features

- Single power supply operation (3.3V or 5.0V) or dual power supply operation (± 1.65 to ± 2.5 V)
- Radiation performance
 - Total dose: > 1 Mrad(Si); Dose rate = 50-300 rad(Si)/s
 - ELDRS Immune
 - SEL Immune > 100 MeV-cm²/mg
 Neutron Displacement Damage > 10¹⁴ neutrons/cm²
- Unity Gain Bandwidth 35 MHz Typical
- Rail-to-Rail input and output range
- Enable pin to Enable/Disable amplifiers in pairs.
- · Short Circuit Tolerant
- Full military temperature range
- Designed for aerospace and high reliability space applications
- Packaging Hermetic ceramic SOIC
 - 16-pin, .417"L x .300"W x .120"Ht
 - Weight 0.8 grams max
- Radiation Hardness Assurance Plan: DLA Certified to MIL-PRF-38534, Appendix G.

General Description

The RHD5902 is a radiation hardened, single supply, high speed quad operational amplifier with enable in a 16-pin SOIC package. The RHD5902 design uses specific circuit topology and layout methods to mitigate total ionizing dose effects and single event latchup. These characteristics make the RHD5902 especially suited for the harsh environment encountered in Deep Space missions. It is guaranteed operational from -55°C to +125°C. Available screened in accordance with MIL-PRF-38534 Class K, the RHD5902 is ideal for demanding military and space applications.

Organization and Application

The RHD5902 amplifiers are capable of rail-to-rail input and outputs. Performance characteristics listed are for general purpose operational 5V CMOS amplifier applications. The amplifiers will drive substantial resistive or capacitive loads and are unity gain stable under normal conditions. Resistive loads in the low kohm range can be handled without gain derating and capacitive loads of several nF can be tolerated. CMOS device drive has a negative temperature coefficient and the devices are therefore inherently tolerant to momentary shorts, although on chip thermal shutdown is not provided. All inputs and outputs are diode protected.

The devices will not latch with SEU events to above $100 \text{ MeV-cm}^2/\text{mg}$. Total dose degradation is minimal to above 1 Mrad(Si). Displacement damage environments to neutron fluence equivalents in the mid 10^{14} neutrons per cm² range are readily tolerated. There is no sensitivity to low-dose rate (ELDRS) effects. SEU effects are application Dependent.

The RHD5902 is configured with enable/disable control. Pairs of amplifiers are put in a power-down condition with their outputs in a high impedance state. Several useful operational amplifier configurations are supported where more than one amplifier can feed an output with others disabled.



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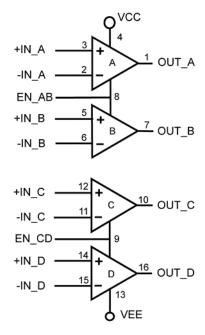


Figure 1: Block Diagram

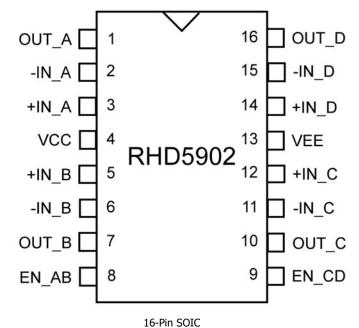


Figure 2: Package Pin-Out

Notes:

- 1) Package and Lid are electrically isolated from signal pads.
- 2) It is recommended that the Lid be grounded to prevent any ESD or static buildup.
- 3) EN_AB enables amplifiers A & B. EN_CD enables amplifiers C & D.



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Table 1: Pin-Out Description

Pin	Signal Name	Definition
1	OUT_A	Output of Amplifier A.
2	-IN_A	Inverting input of Amplifier A.
3	+IN_A	Non-Inverting input of Amplifier A.
4	VCC	+ Voltage Supply.
5	+IN_B	Non-Inverting input of Amplifier B.
6	-IN_B	Inverting input of Amplifier B.
7	OUT_B	Output of Amplifier B.
8	EN_AB	A Logic Low will disable Amplifiers A & B so that the outputs are high impedance.
9	EN_CD	A Logic Low will disable Amplifiers C & D so that the outputs are high impedance.
10	OUT_C	Output of Amplifier C.
11	-IN_C	Inverting input of Amplifier C.
12	+IN_C	Non-Inverting input of Amplifier C.
13	VEE	- Voltage Supply.
14	+IN_D	Non-Inverting input of Amplifier D.
15	-IN_D	Inverting input of Amplifier D.
16	OUT_D	Output of Amplifier D.

Absolute Maximum Ratings

Parameter	Range	Units
Case Operating Temperature Range	-55 to +125	°C
Storage Temperature Range	-65 to +150	°C
Junction Temperature	+150	°C
Supply Voltage V _{CC} - V _{EE}	+7.0	V
Input Voltage	V _{CC} +0.4 V _{EE} -0.4	٧
Lead Temperature (soldering, 10 seconds)	300	°C
Thermal Resistance, Junction to Case, ⊖jc	7	°C/W
Power @ 25°C	200	mW

Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress rating only; functional operation beyond the "Operation Conditions" is not recommended and extended exposure beyond the "Operation Conditions" may affect device reliability.



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Recommended Operating Conditions

Symbol Parameter		Typical	Units
+V _{CC}	Power Supply Voltage	3.3 to 5.0	V
Vcm Input Common Mode Range		V_{CC} to V_{EE}	V

Electrical Performance Characteristics

 $(T_C = -55^{\circ}C \text{ To } +125^{\circ}C, +V_{CC} = +5.0V -- \text{ Unless Otherwise Specified})$

Parameter	Symbol	Conditions	MIN	MAX	Units
Input Offset Voltage 1/	V _{OS}		-4	4	mV
Input Offset Current 1/	Ios		-100	100	рА
Input Bias Current <u>1</u> /	т	$T_C = +25^{\circ}C, -55^{\circ}C$	-100	100	рА
Triput bias Current <u>1</u> /	I_{B}	$T_{C} = +125^{\circ}C$	-1000	1000	
Common Mode Rejection Ratio	CMRR		60		dB
Power Supply Rejection Ratio	PSRR		70		dB
Output Voltage High	V _{OH}	$R_{OUT} = 720$ ohms to GND	4.9		V
Output Voltage Low	V _{OL}	$R_{OUT} = 720$ ohms to V_{CC}		0.1	V
Short Circuit	I _{O(SINK)}	V _{OUT} to V _{CC}	-130	-290	mA
Output Current 2/	I _{O(SOURCE)}	V _{OUT} to V _{EE}	110	210	mA
Slew Rate 1/	SR	$R_L = 8K$, $Gain = 1$	12		V/uS
Open Loop Gain 1/	A _{OL}	No Load	90		dB
Unity Gain Bandwidth <u>1</u> /	UGBW	35 Typical @ $R_L = 10K$	23		MHz
Input Voltage - Enable <u>2</u> /	V _{HI}	High (Enabled)	3.5		V
(EN_AB, EN_CD)	V _{LO}	Low (Disabled)		1.5	V
Input Current - Enable <u>2</u> / (EN_AB, EN_CD)	${ m I}_{\sf EN}$			10	nA
Ovices and Comply Compant 1/	т	All Amplifiers Enabled, No Load		5.5	mA
Quiescent Supply Current 1/	I_{CCQ}	All Amplifier Disabled 2/		300	nA
Channel Separation 2/		$R_L = 2K, f = 1.0KHz$	84		dB
Input-Referred Voltage Noise 2/	e _n	46 Typical @ F = 5 kHz			nV/√Hz
Phase Margin 2/	Φ_{m}		30		Deg

Notes:

- 1) Specification derated to reflect Total Dose exposure to 1 Mrad(Si) @ +25°C.
- 2) Not tested. Shall be guaranteed by design, characterization, or correlation to other test parameters.



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Switching Characteristics

 $(T_C = -55^{\circ}C \text{ To } +125^{\circ}C, +V_{CC} = +5.0V -- \text{ Unless Otherwise Specified})$

Parameter	Symbol	Conditions	MIN	MAX	Units
Output Delay (Enabled) 2/	t _{on} EN			500	ns
Output Delay (Disabled) 2/	t _{OFF} EN			100	ns

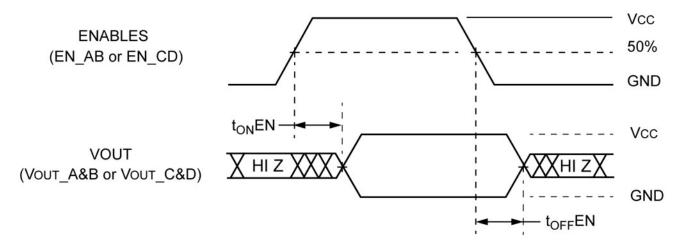
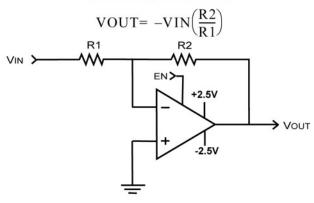


Figure 3: RHD5902 Switching Diagram

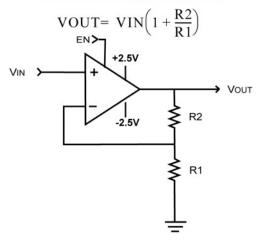
RHD5902 Quad Operational Amplifier Application Notes

Application Note 1: Dual Power Supply Amplifier

Inverting Amplifier



Non Inverting Amplifier

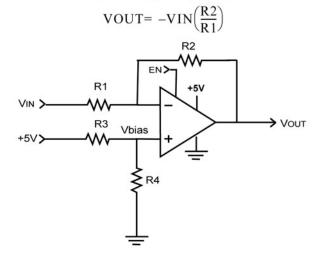


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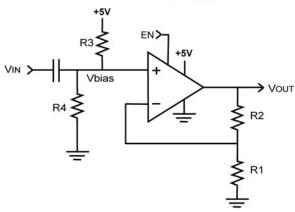
Application Note 2: Single Power Supply Amplifier

Inverting Amplifier



Non Inverting Amplifier

VOUT= VIN
$$\left(1 + \frac{R2}{R1}\right)$$



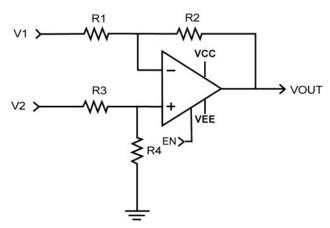
Note:

For V_{OUT} DC @ mid range of common mode voltage range, $V_{BIAS} = 2.5/(1+R2/R1)$, $V_{BIAS} = +5*R4/(R3+R4)$

Application Note 3: Differential Input Amplifier

Differential Input Amplifier

$$VOUT \ = \ \left(V2 \bigg(\frac{R4}{R3 + R4}\bigg) \bigg(1 + \frac{R2}{R1}\bigg)\right) - \bigg(V1 \frac{R2}{R1}\bigg)$$

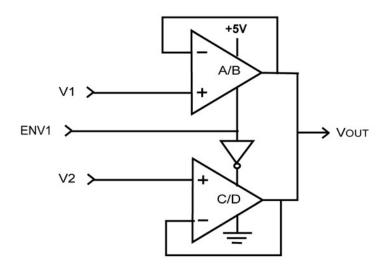


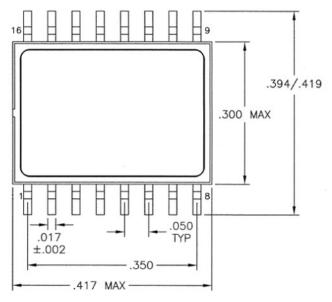
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Application Note 4: Multiple Amplifiers

Multiple Amplifiers - Selectable Output





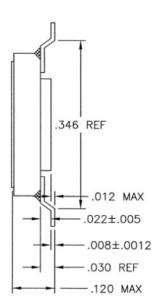


Figure 4: Package Outline

Note:

Package and lid are electrically isolated from signal pads.



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Ordering Information

Model	DLA SMD #	Screening	Package
RHD5902-7	-	Commercial Flow, +25°C testing only	
RHD5902-S	-	Military Temperature, -55°C to +125°C Screened in accordance with the individual Test Methods of MIL-STD-883 for Space Applications	16-pin
RHD5902- 201-1S	5962-1024103KXC	In accordance with DLA SMD	SOIC Package
RHD5902- 201-2S	5962-1024103KXA	The accordance with DEA SMD	J
RHD5902- 901-1S	5962H1024103KXC	In accordance with DLA Certified RHA Program Plan to	
RHD5902- 901-2S	5962H1024103KXA	RHA Level "H", 1 Mrad(Si)	

Revision History

Date	Revision	Change Description	
03/28/2016	С	Import into CAES format	
03/08/2021	D	evised Per ECN 23542	





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Datasheet Definitions

	DEFINITION
Advanced Datasheet	CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is still in the development stage and the datasheet is subject to change . Specifications can be TBD and the part package and pinout are not final .
Preliminary Datasheet	CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is in the characterization stage and prototypes are available.
Datasheet	Product is in production and any changes to the product and services described herein will follow a formal customer notification process for form, fit or function changes.

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